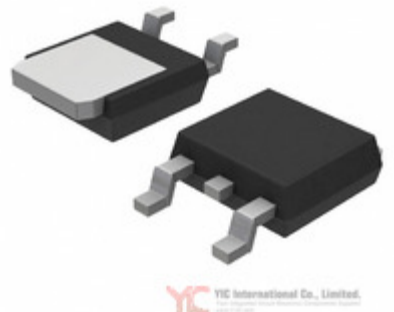


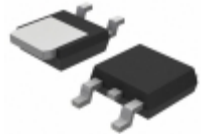
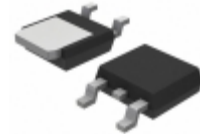
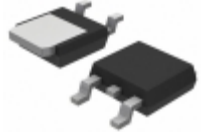
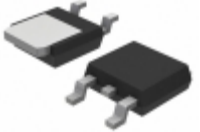
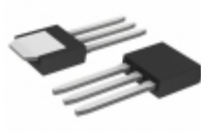

	<p>Hersteller-Teilenummer: NTD18N06LG</p>
	<p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p>
	<p>Teil der Beschreibung: MOSFET N-CH 60V 18A DPAK</p>
	<p>Datenblätter:  NTD18N06LG.pdf</p>
	<p>RoHs Status: Bleifrei / RoHS-konform</p>
	<p>Lagerzustand: New original, 6249 pcs Stock Available.</p>
	<p>Liefern von: Hong Kong</p>
<p>Image may be representation. See specs for product details.</p>	<p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>

Spezifikationen

Teilenummer	NTD18N06LG
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 60V 18A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	6249 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (Tj)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	2.1W (Ta), 55W (Tj)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	18A (Ta)
Rds On (Max) @ Id, Vgs	65 mOhm @ 9A, 5V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	22nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	675pF @ 25V
Verpackung	Tube
















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Sie können auch interessiert sein:

 <p>NTD18N06-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 18A IPAK</p>	 <p>NTD20N03G O NTD20N03G O</p>	 <p>NTD18N06T4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 18A DPAK</p>	 <p>NTD18N06LT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 18A DPAK</p>
 <p>NTD18N06L AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 18A DPAK</p>	 <p>NTD18N06LT4 AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 18A DPAK</p>	 <p>NTD18N06L-001 AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 18A IPAK</p>	 <p>NTD20N03 ON NTD20N03 ON</p>

heiße Teile

Mehr

 NTD14N03G	 NTD14N03R	 NTD14N03R-001	 NTD14N03R-1	 NTD14N03R-1G
 NTD14N03RG	 NTD14N03RT4	 NTD14N03RT4G	 NTD14N03RTCG	 NTD14N03T4G
 NTD15N06	 NTD15N06L	 NTD15N06LG	 NTD15N06LT4	 NTD15N06LT4G
 NTD15N06T4	 NTD15N06T4G	 NTD15N06VLT4	 NTD15N07	 NTD15N10
 NTD18N06-001	 NTD18N06-1G	 NTD18N06G	 NTD18N06L	 NTD18N06L-1G
 NTD18N06LT4G	 NTD18N06T4G	 NTD20N03	 NTD20N03G	 NTD20N03HL
 NTD20N03L27	 NTD20N03L27G	 NTD20N03L27T	 NTD20N03L27T4	 NTD20N03L27T4G
 NTD20N03RT4G	 NTD20N06	 NTD20N06-001	 NTD20N06-1G	 NTD20N06HD
 NTD20N06HDLT4G	 NTD20N06HL	 NTD20N06L	 NTD20N06L-001	 NTD20N06L-1G
 NTD20N06LG	 NTD20N06LT4	 NTD20N06LT4G	 NTD20N06T4G	 NTD20N06V

Contact us:Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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